NSN 5961-00-152-7993

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View Online at https://aerobasegroup.com/nsn/5961-00-152-7993 **Inclosure Material:** Glass and metal **Overall Length:** 1.000 inches **Overall Diameter:** 1.000 inches **End Application:** Kilauea class t-ae 26; bob hope class t-akr 300; sirius class t-afs 8 **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-8 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.375 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, peak **Current Rating Per Characteristic:** 150.00 amperes average forward current averaged over a full 60-hz cycle **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Weapon system essential **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release4936 professional/industrial association specification Shelf Life: N/a

Unit Of Measure:

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Demilitarization:

No

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